



# Low Power, Rail-to-Rail Output, Precision JFET Amplifiers

## Data Sheet

## AD8641/AD8642/AD8643

### FEATURES

- Low supply current: 250  $\mu$ A max
- Very low input bias current: 1 pA max
- Low offset voltage: 750  $\mu$ V max
- Single-supply operation: 5 V to 26 V
- Dual-supply operation:  $\pm$ 2.5 V to  $\pm$ 13 V
- Rail-to-rail output
- Unity-gain stable
- No phase reversal
- SC70 package

### APPLICATIONS

- Line-/battery-powered instruments
- Photodiode amplifiers
- Precision current sensing
- Medical instrumentation
- Industrial controls
- Precision filters
- Portable audio
- ATE

### GENERAL DESCRIPTION

The AD8641/AD8642/AD8643 are low power, precision JFET input amplifiers featuring extremely low input bias current and rail-to-rail output. The ability to swing nearly rail-to-rail at the input and rail-to-rail at the output enables designers to buffer CMOS DACs, ASICs, and other wide output swing devices in single-supply systems. The outputs remain stable with capacitive loads of more than 500 pF.

The AD8641/AD8642/AD8643 are suitable for applications utilizing multichannel boards that require low power to manage heat. Other applications include photodiodes, ATE reference level drivers, battery management, and industrial controls.

The AD8641/AD8642/AD8643 are fully specified over the extended industrial temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ . The AD8641 is available in 5-lead SC70 and 8-lead SOIC lead-free packages. The AD8642 is available in 8-lead MSOP and 8-lead SOIC lead-free packages. The AD8643 is available in 14-lead SOIC and 16-lead, 3 mm  $\times$  3 mm, LFCSP lead-free packages.

### PIN CONFIGURATIONS

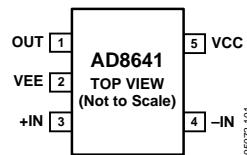


Figure 1. 5-Lead SC70 (KS-5)



Figure 2. 8-Lead SOIC (R-8)

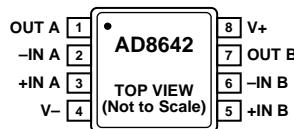


Figure 3. 8-Lead SOIC (R-8)



Figure 4. 8-Lead MSOP (RM-8)

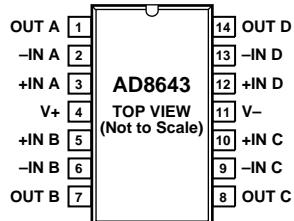
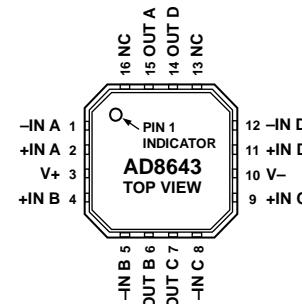


Figure 5. 14-Lead SOIC (R-14)



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NOTES  
1. NC = NO CONNECT.  
2. EXPOSED PAD SHOULD BE CONNECTED TO V+.

Figure 6. 16-Lead LFCSP (CP-16) (Not Drawn to Scale)

### Rev. E

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One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.  
Tel: 781.329.4700 [www.analog.com](http://www.analog.com)  
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## REVISION HISTORY

### 9/11—Rev. D to Rev. E

Changes to Thermal Resistance Section..... 5

### 7/11—Rev. C to Rev. D

Changes to Figure 6..... 1

### 11/10—Rev. B to Rev. C

Changes to Figure 6..... 1

Added Thermal Resistance Section and Table 4 ..... 5

Updated Outline Dimensions .....

13

Changes to Ordering Guide .....

15

### 4/05—Rev. A to Rev. B

Added AD8643 .....

Universal

Added 14-Lead SOIC.....

Universal

Added 16-Lead LFCSP.....

Universal

Updated Outline Dimensions .....

13

Changes to Ordering Guide .....

14

### 3/05—Rev. 0 to Rev. A

Added AD8642 .....

Universal

Changes to General Description .....

1

Added Figure 3 and Figure 4.....

1

Changes to Specifications.....

3

Changes to Absolute Maximum Ratings.....

5

Changes to Figure 22.....

8

Changes to Figure 23.....

9

Changes to Figure 41.....

12

Updated Outline Dimensions .....

13

Changes to Ordering Guide .....

14

### 10/04—Initial Version: Revision 0

## SPECIFICATIONS

### ELECTRICAL CHARACTERISTICS

$V_S = 5.0 \text{ V}$ ,  $V_{CM} = 2.5 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$	AD8643 LFCSP only $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $+85^\circ\text{C} < T_A < +125^\circ\text{C}, V_{CM} = 1.5 \text{ V}$	50	750	1	$\mu\text{V}$
Input Bias Current	$I_B$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	0.25	1	1.5	$\text{mV}$
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		180	0.5	$\text{pA}$
Input Voltage Range			0	3	60	$\text{pA}$
Common-Mode Rejection Ratio	CMRR	$V_{CM} = 0 \text{ V to } 2.5 \text{ V}$	74	93		$\text{dB}$
Large Signal Voltage Gain	$A_{VO}$	$R_L = 10 \text{ k}\Omega, V_O = 0.5 \text{ to } 4.5 \text{ V}$	80	140		$\text{V/mV}$
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		2.5		$\mu\text{V}/^\circ\text{C}$
OUTPUT CHARACTERISTICS						
Output Voltage High	$V_{OH}$		4.95			$\text{V}$
Output Voltage Low	$V_{OL}$	$I_L = 1 \text{ mA}, -40^\circ\text{C} \text{ to } +125^\circ\text{C}$	4.94		0.05	$\text{V}$
Output Current	$I_{OUT}$	$I_L = 1 \text{ mA}, -40^\circ\text{C} \text{ to } +125^\circ\text{C}$		0.01	0.05	$\text{mA}$
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_S = 5 \text{ V to } 26 \text{ V}$	90	107		$\text{dB}$
Supply Current/Amplifier	$I_{SY}$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		195	250	$\mu\text{A}$
					270	$\mu\text{A}$
DYNAMIC PERFORMANCE						
Slew Rate	SR		2			$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP	AD8641, AD8642 AD8643	3			$\text{MHz}$
Phase Margin	$\emptyset_m$		2.5			$\text{MHz}$
			50			Degrees
NOISE PERFORMANCE						
Voltage Noise	$e_N \text{ p-p}$	$f = 0.1 \text{ Hz to } 10 \text{ Hz}$	4.0			$\mu\text{V p-p}$
Voltage Noise Density	$e_N$	$f = 1 \text{ kHz}$	28.5			$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_N$	$f = 1 \text{ kHz}$	0.5			$\text{fA}/\sqrt{\text{Hz}}$

$V_S = \pm 13$  V,  $V_{CM} = 0$  V,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 2.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$	AD8643 LFCSP only $-40^\circ < T_A < +125^\circ\text{C}$	70	750	1	$\mu\text{V}$
					1.5	$\text{mV}$
Input Bias Current	$I_B$	$-40^\circ < T_A < +125^\circ\text{C}$	0.25	1	260	$\text{pA}$
Input Offset Current	$I_{OS}$	$-40^\circ < T_A < +125^\circ\text{C}$			0.5	$\text{pA}$
Input Voltage Range					65	$\text{pA}$
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -13$ V to $+10$ V	-13	107	+10	V
Large Signal Voltage Gain	$A_{VO}$	$R_L = 10 \text{ k}\Omega$ , $V_O = -11$ V to $+11$ V	90	107	215	dB
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ < T_A < +125^\circ\text{C}$			2.5	$\mu\text{V}/^\circ\text{C}$
OUTPUT CHARACTERISTICS						
Output Voltage High	$V_{OH}$		+12.95			V
Output Voltage Low	$V_{OL}$	$I_L = 1 \text{ mA}$ , $-40^\circ\text{C}$ to $+125^\circ\text{C}$	+12.94		-12.95	V
		$I_L = 1 \text{ mA}$ , $-40^\circ\text{C}$ to $+125^\circ\text{C}$			-12.94	V
Output Current	$I_{OUT}$			$\pm 12$		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 2.5$ V to $\pm 13$ V	90	107	200	dB
Supply Current/Amplifier	$I_{SY}$	$-40^\circ < T_A < +125^\circ\text{C}$		290	330	$\mu\text{A}$
DYNAMIC PERFORMANCE						
Slew Rate	SR			3		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			3.5		MHz
Phase Margin	$\emptyset_m$			60		Degrees
NOISE PERFORMANCE						
Voltage Noise	$e_N \text{ p-p}$	$f = 0.1 \text{ Hz}$ to $10 \text{ Hz}$		4.2		$\mu\text{V p-p}$
Voltage Noise Density	$e_N$	$f = 1 \text{ kHz}$		27.5		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_N$	$f = 1 \text{ kHz}$		0.5		$\text{fA}/\sqrt{\text{Hz}}$

## ABSOLUTE MAXIMUM RATINGS

Absolute maximum ratings apply at 25°C, unless otherwise noted.

**Table 3.**

Parameter	Rating
Supply Voltage	27.3 V
Input Voltage	VS– to VS+ ±Supply Voltage
Differential Input Voltage	Indefinite
Output Short-Circuit Duration	
Storage Temperature Range KS-5, R-8, RM-8, R-14, CP-16 Packages	–65°C to +150°C
Operating Temperature Range	–40°C to +125°C
Junction Temperature Range KS-5, R-8, RM-8, R-14, CP-16 Packages	–65°C to +150°C
Lead Temperature (Soldering, 60 sec)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL RESISTANCE

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages. This was measured using a standard 4-layer board. For the LFCSP package, solder the exposed pad to a copper plane, which should be connected to V+.

**Table 4.**

Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
5-Lead SC70 (KS)	430	149	°C/W
8-Lead SOIC (R)	121	43	°C/W
8-Lead MSOP (RM)	142	45	°C/W
14-Lead SOIC (R)	110	36	°C/W
16-Lead LFCSP (CP)	81	16	°C/W

## ESD CAUTION



### ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## TYPICAL PERFORMANCE CHARACTERISTICS

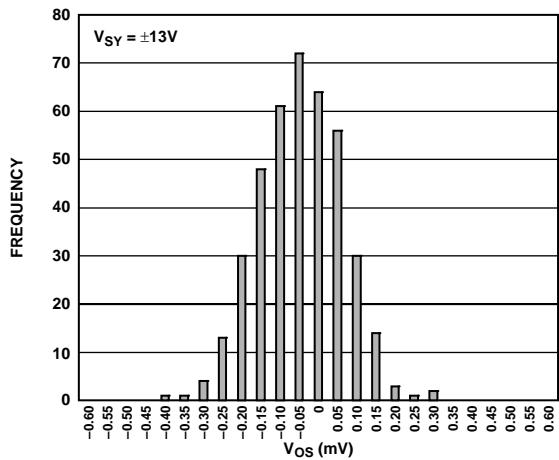


Figure 7. Input Offset Voltage

05072-002

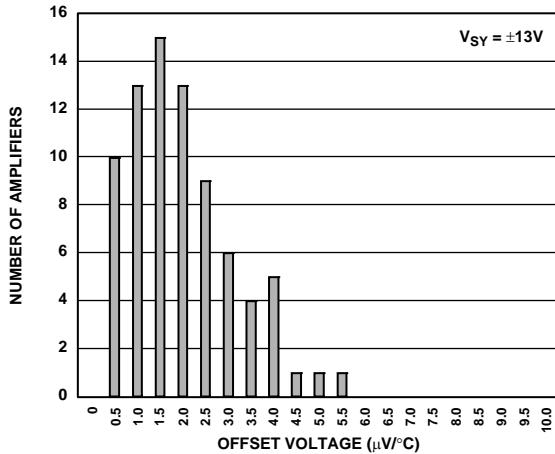


Figure 8. Offset Voltage Drift

05072-003

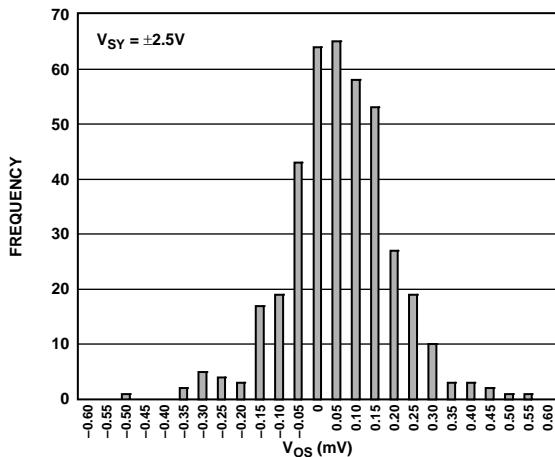
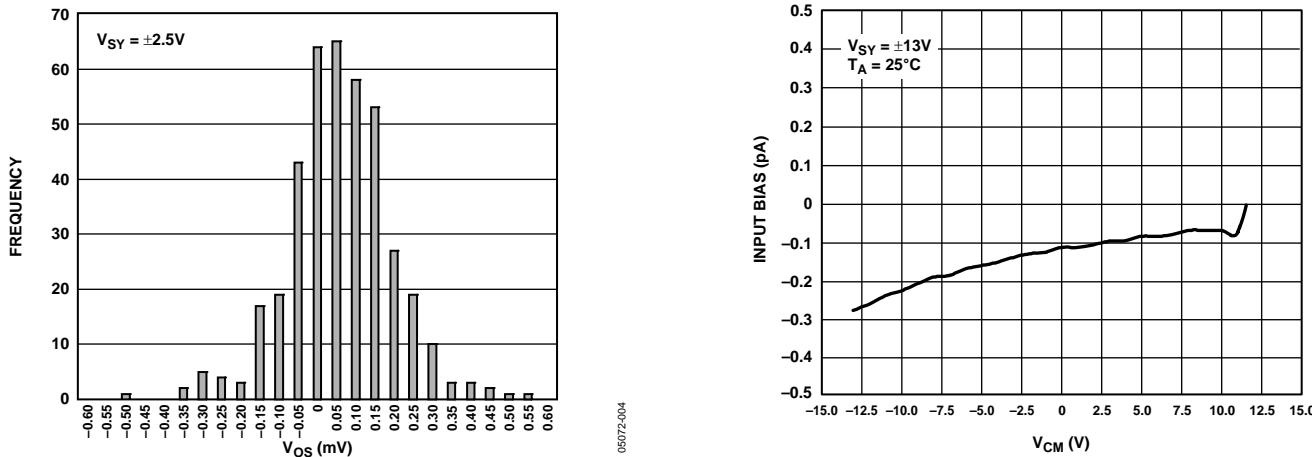
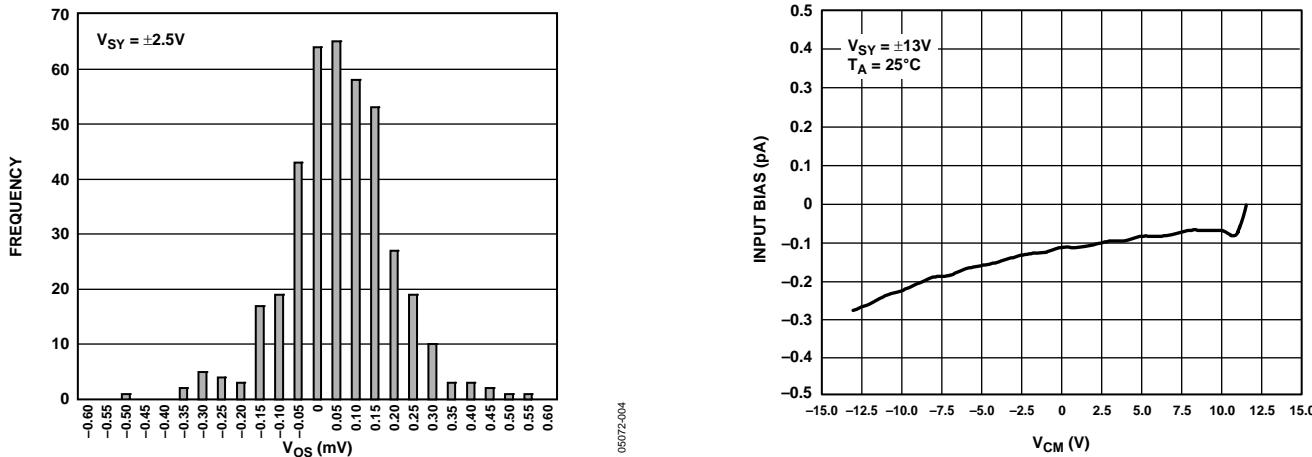


Figure 9. Input Offset Voltage

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Figure 11. Input Bias Current vs.  $V_{CM}$ 

05072-006

Figure 12. Input Bias Current vs.  $V_{CM}$ 

05072-007

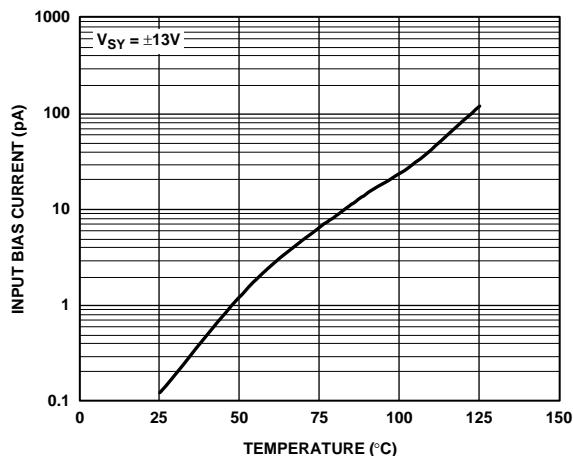
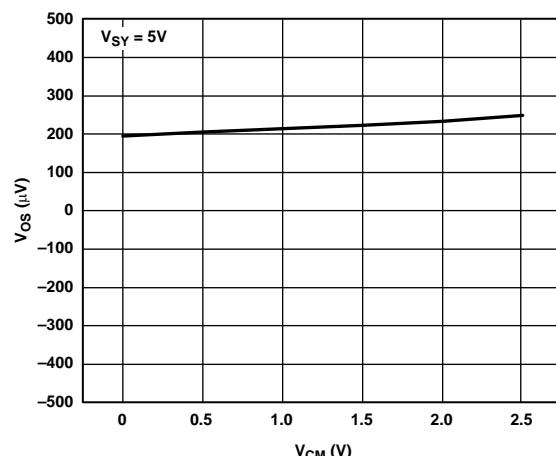
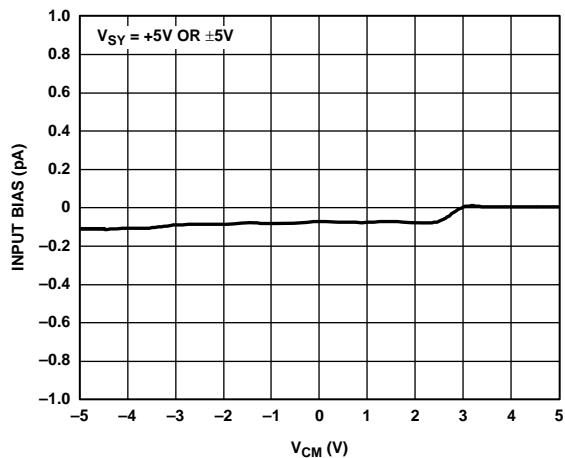


Figure 13. Input Bias Current vs. Temperature

05072-008

Figure 16. Input Offset Voltage vs.  $V_{CM}$ 

05072-011

Figure 14. Input Bias Current vs.  $V_{CM}$ 

05072-009

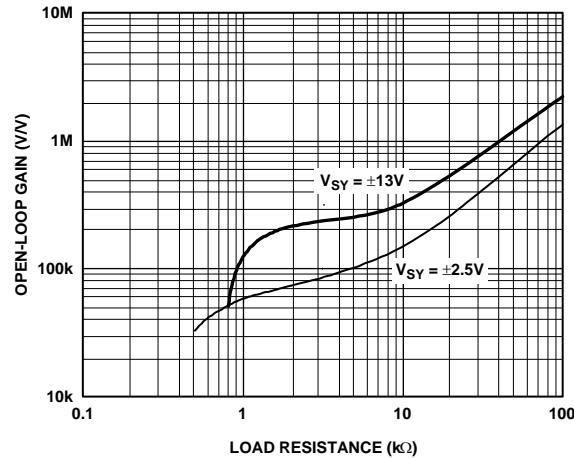
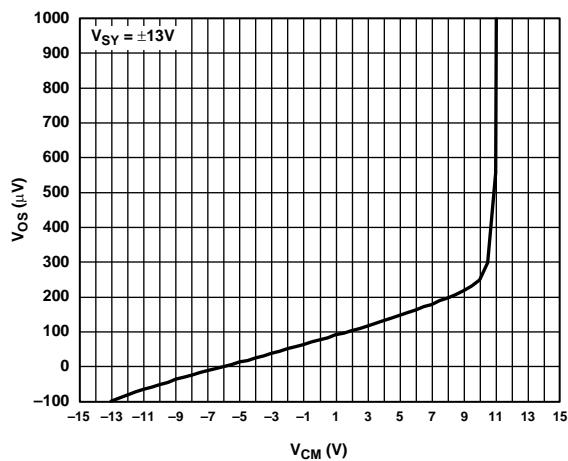


Figure 17. Open-Loop Gain vs. Load Resistance

05072-012

Figure 15. Input Offset Voltage vs.  $V_{CM}$ 

05072-009

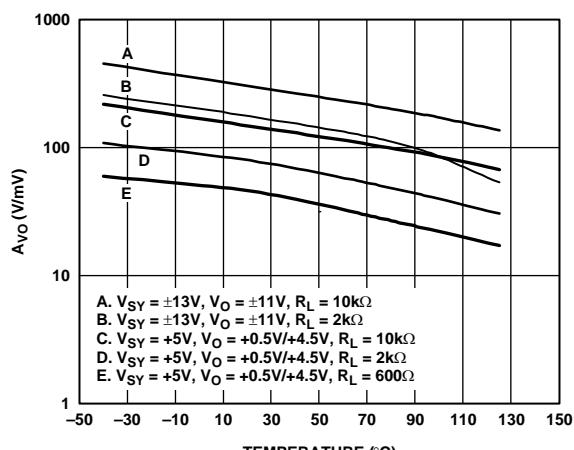


Figure 18. Open-Loop Gain vs. Temperature

05072-013

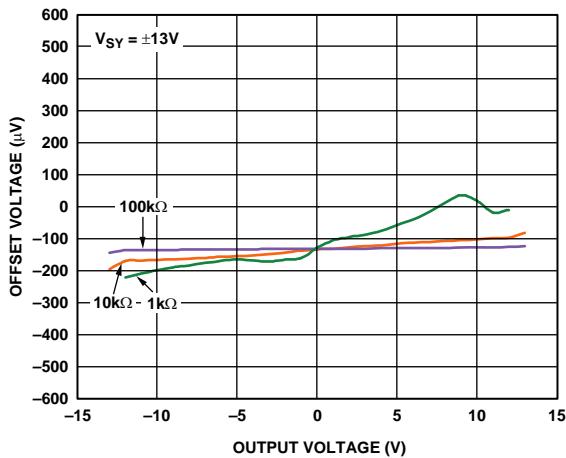
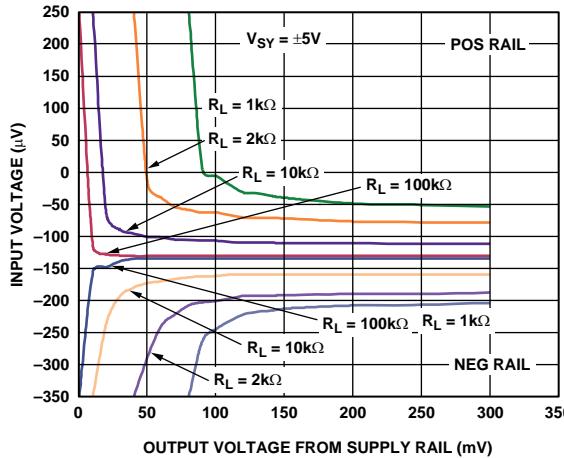


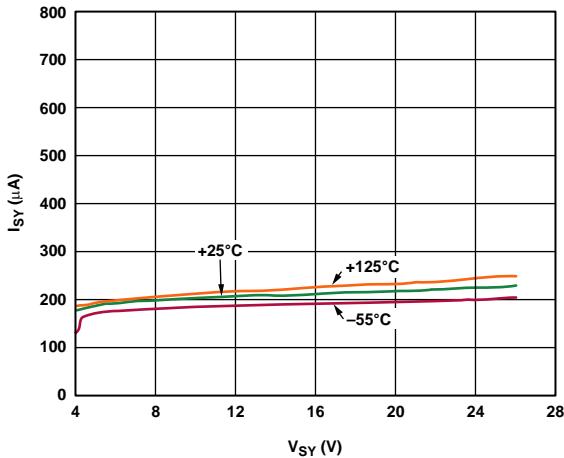
Figure 19. Input Error Voltage vs. Output Voltage for Resistive Loads

05072-014



05072-015

Figure 20. Input Error Voltage vs. Output Voltage Within 300 mV of Supply Rails



05072-016

Figure 21. Quiescent Current vs. Supply Voltage at Different Temperatures

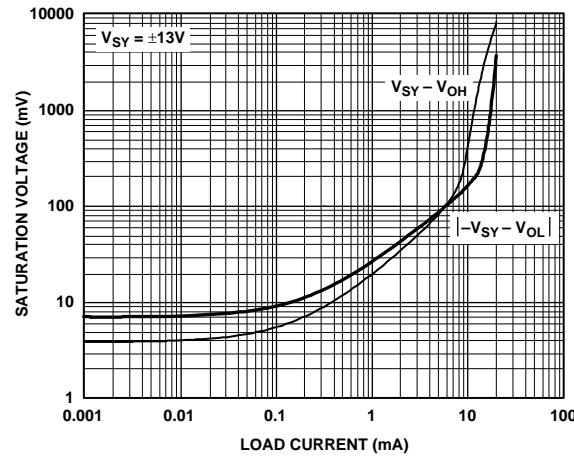
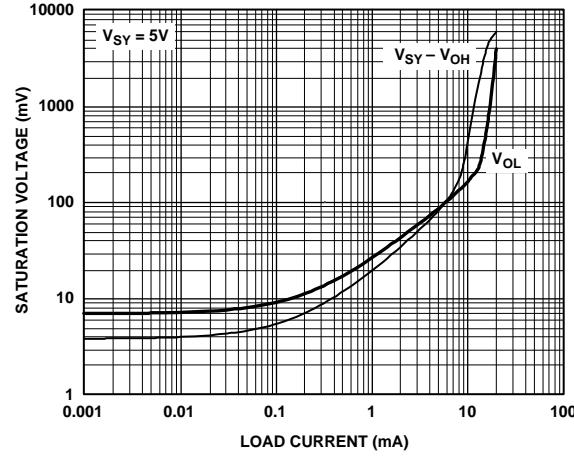


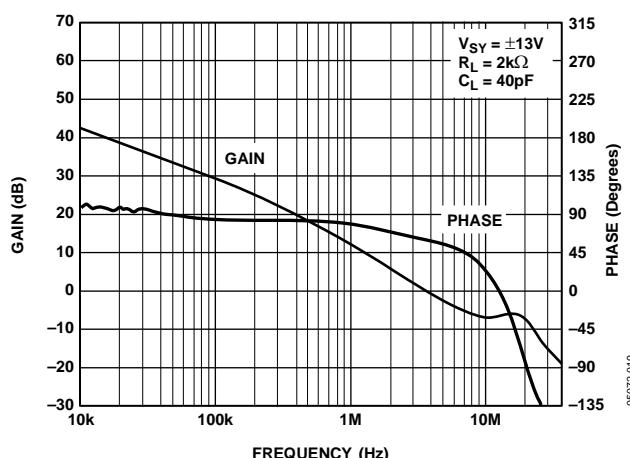
Figure 22. Output Saturation Voltage vs. Load Current

05072-017



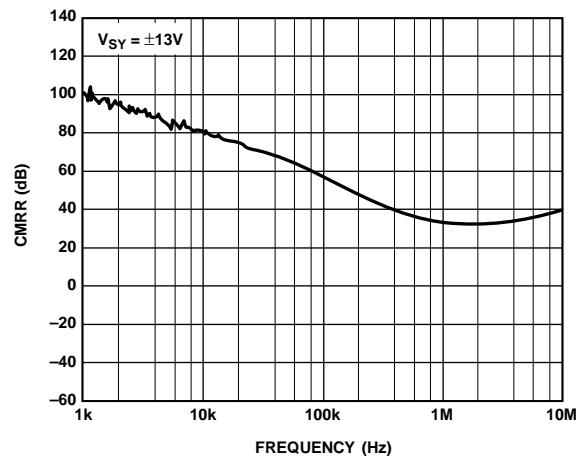
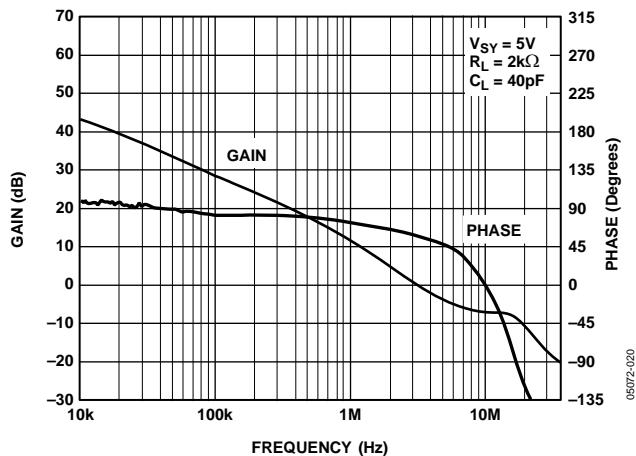
05072-018

Figure 23. Output Saturation Voltage vs. Load Current

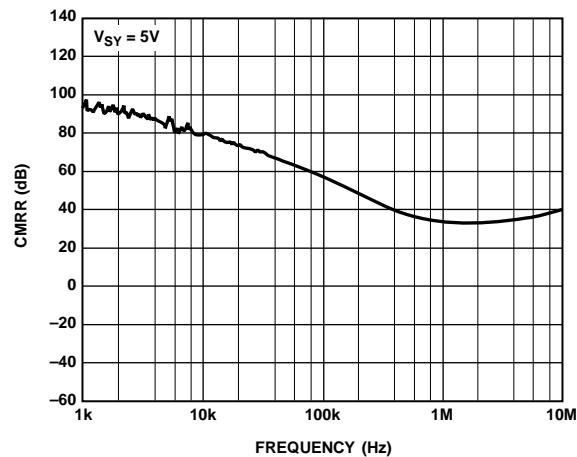
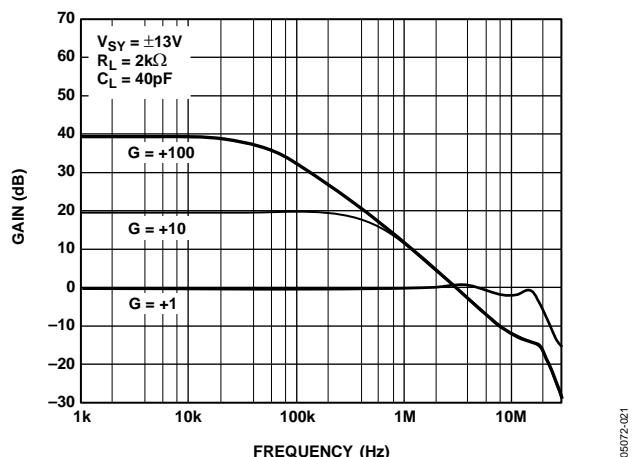


05072-019

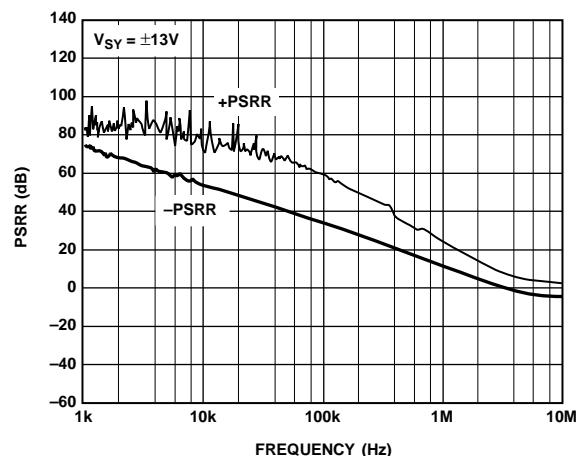
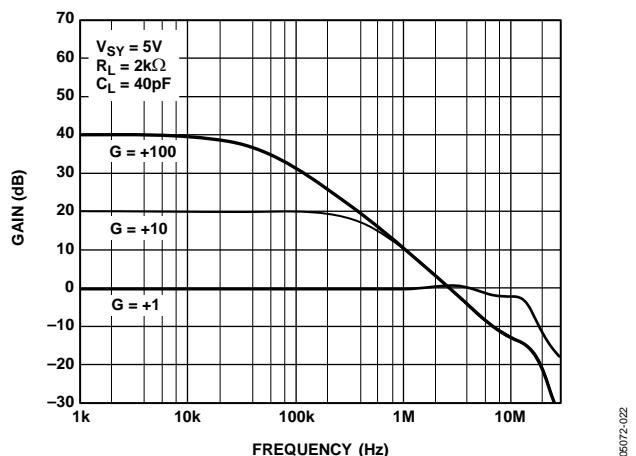
Figure 24. Open-Loop Gain and Phase Margin vs. Frequency



05072-023



05072-024



05072-025

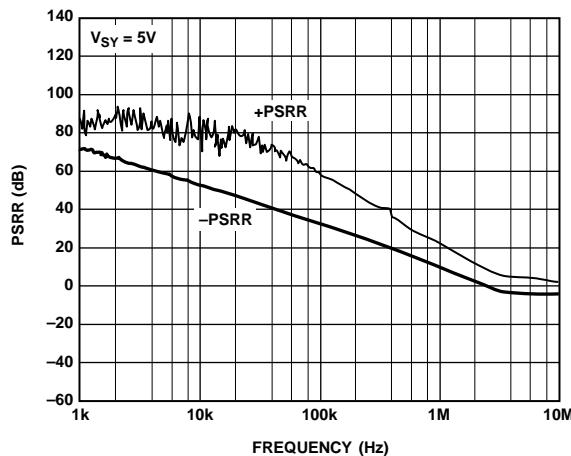


Figure 31. PSRR vs. Frequency

05072-026

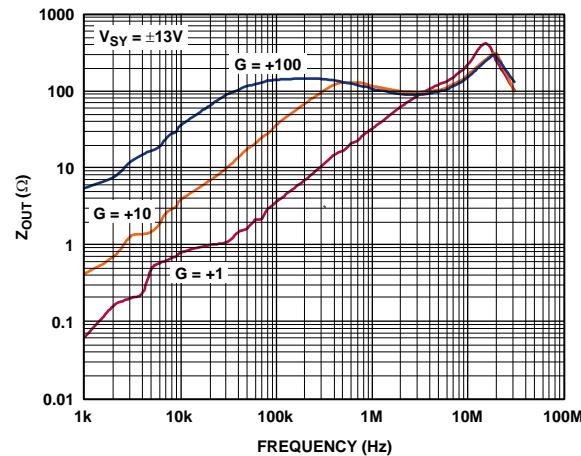


Figure 32. Output Impedance vs. Frequency

05072-027

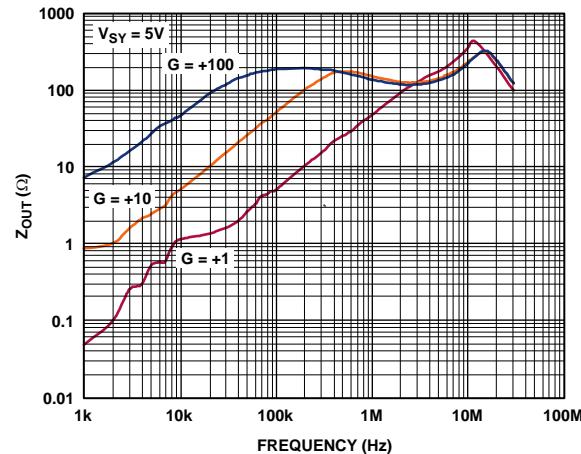


Figure 33. Output Impedance vs. Frequency

05072-028

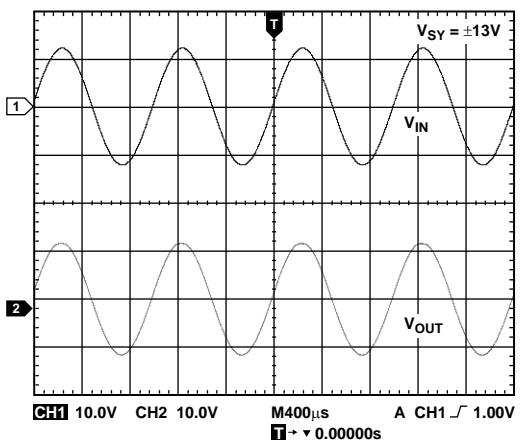


Figure 34. No Phase Reversal

05072-029

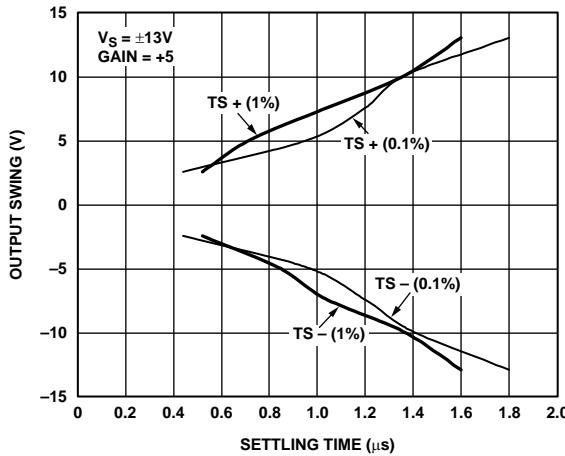


Figure 35. Output Swing and Error vs. Settling Time

05072-030

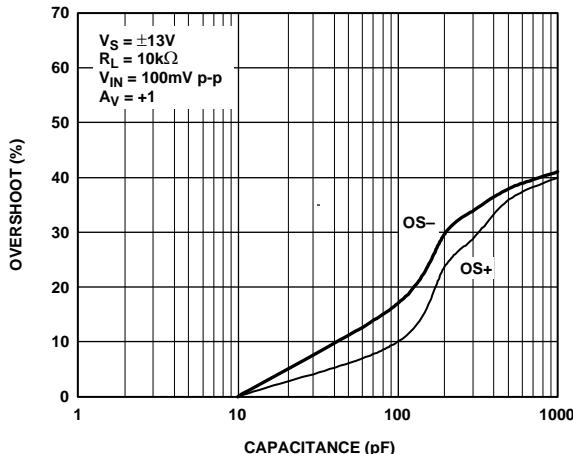


Figure 36. Small Signal Overshoot vs. Load Capacitance

05072-031

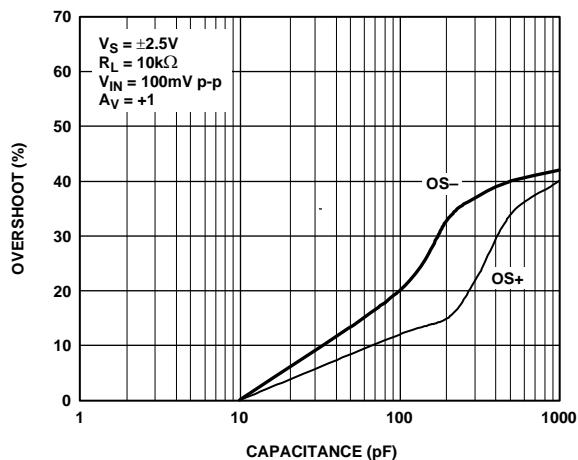


Figure 37. Small Signal Overshoot vs. Load Capacitance

05072-032

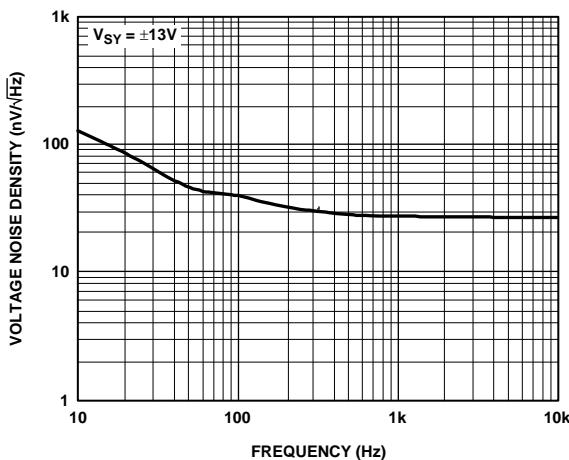


Figure 40. Voltage Noise Density

05072-035

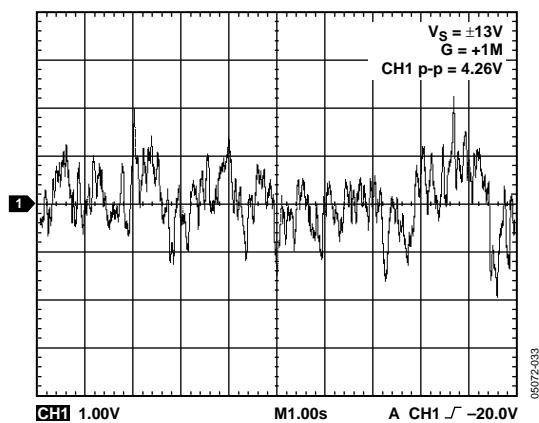


Figure 38. 0.1 Hz to 10 Hz Noise

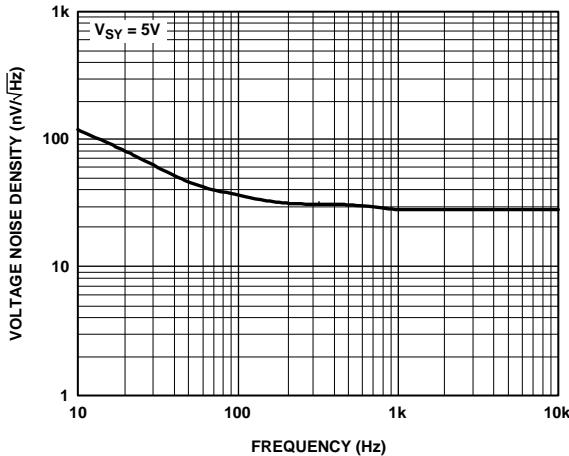


Figure 41. Voltage Noise Density

05072-036

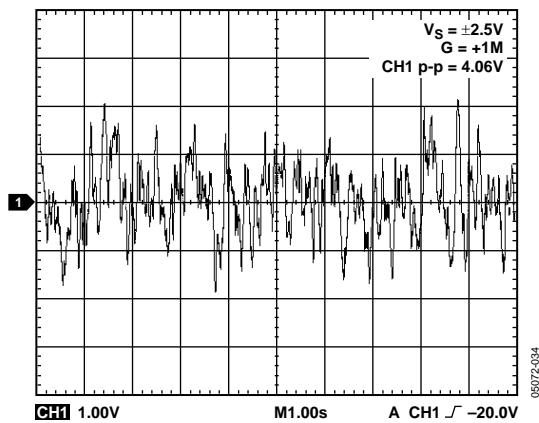


Figure 39. 0.1 Hz to 10 Hz Noise

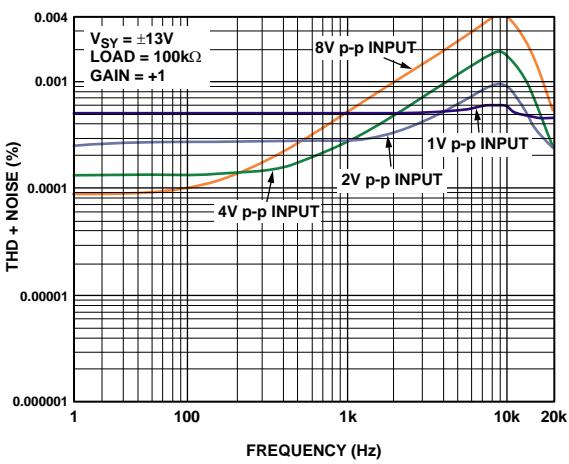


Figure 42. Total Harmonic Distortion + Noise vs. Frequency

05072-037

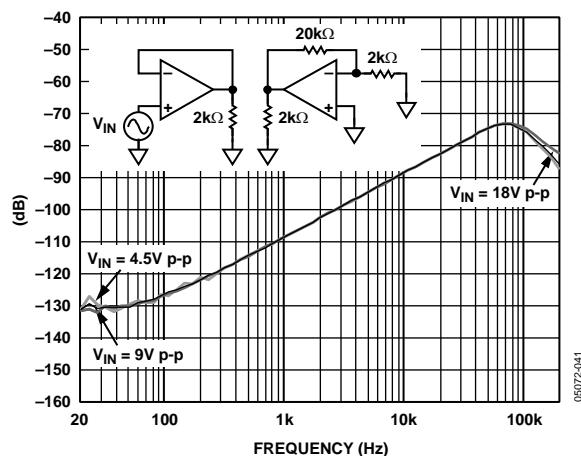
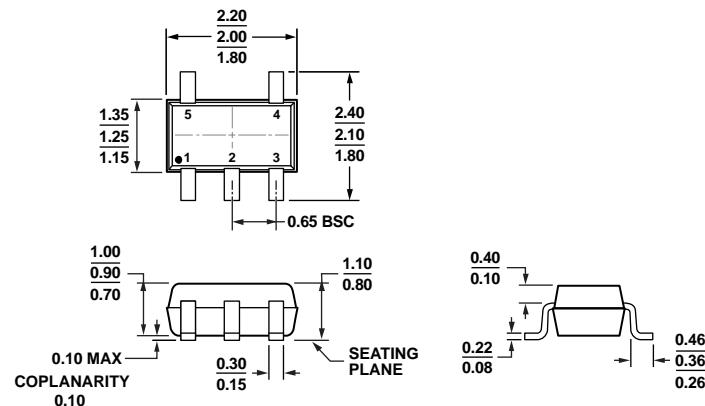


Figure 43. Channel Separation

## OUTLINE DIMENSIONS

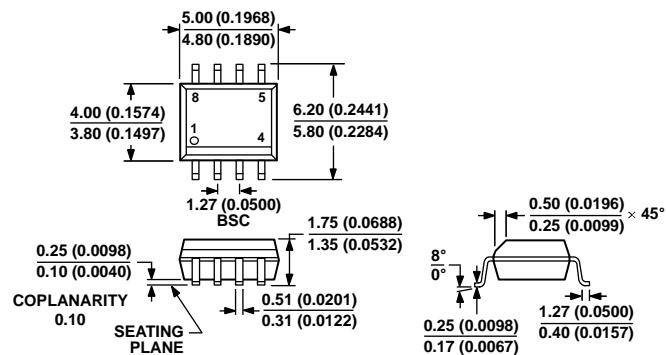


COMPLIANT TO JEDEC STANDARDS MO-203-AA

Figure 44. 5-Lead Thin Shrink Small Outline Transistor Package [SC70]  
(KS-5)

Dimensions shown in millimeters

072809-A



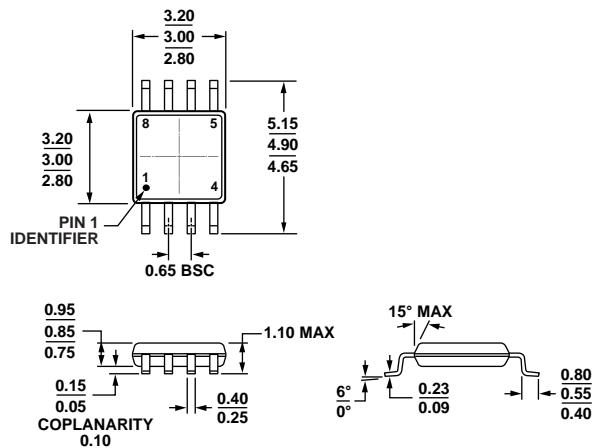
COMPLIANT TO JEDEC STANDARDS MS-012-AA

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

012407-A

Figure 45. 8-Lead Standard Small Outline Package [SOIC\_N]  
(R-8)

Dimensions shown in millimeters and (inches)

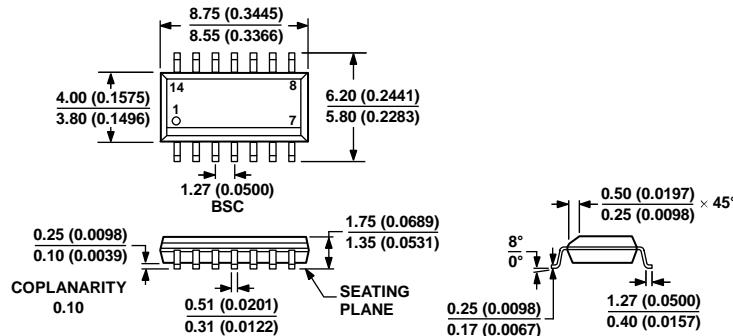


10-07-2009-B

COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 46. 8-Lead Mini Small Outline Package [MSOP]  
(RM-8)

Dimensions shown in millimeters

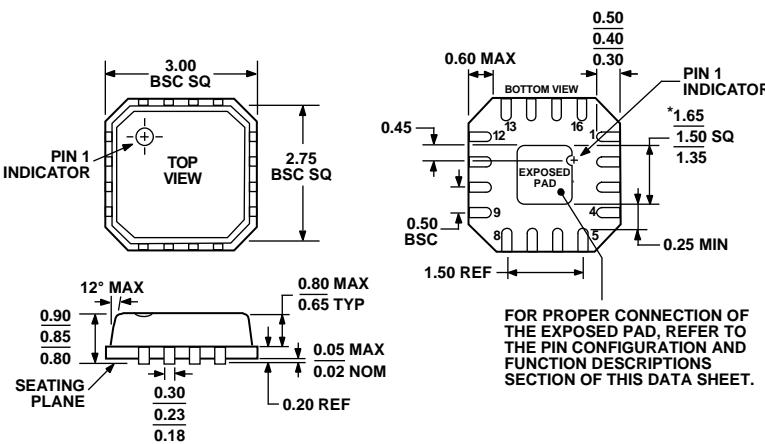


060606-A

COMPLIANT TO JEDEC STANDARDS MS-012-AB

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.Figure 47. 14-Lead Standard Small Outline Package [SOIC\_N]  
(R-14)

Dimensions shown in millimeters and (inches)



07-17-2008-A

\*COMPLIANT TO JEDEC STANDARDS MO-220-VEED-2  
EXCEPT FOR EXPOSED PAD DIMENSION.Figure 48. 16-Lead Lead Frame Chip Scale Package [LFCSP\_VQ]  
3 mm × 3 mm Body, Very Thin Quad (CP-16-3)  
Dimensions shown in millimeters

**ORDERING GUIDE**

<b>Model<sup>1</sup></b>	<b>Temperature Range</b>	<b>Package Description</b>	<b>Package Option</b>	<b>Branding</b>
AD8641AKSZ-R2	–40°C to +125°C	5-Lead SC70	KS-5	A07
AD8641AKSZ-REEL7	–40°C to +125°C	5-Lead SC70	KS-5	A07
AD8641AKSZ-REEL	–40°C to +125°C	5-Lead SC70	KS-5	A07
AD8641ARZ	–40°C to +125°C	8-lead SOIC_N	R-8	
AD8641ARZ-REEL7	–40°C to +125°C	8-lead SOIC_N	R-8	
AD8641ARZ-REEL	–40°C to +125°C	8-lead SOIC_N	R-8	
AD8642ARMZ	–40°C to +125°C	8-lead MSOP	RM-8	A0A
AD8642ARMZ-REEL	–40°C to +125°C	8-lead MSOP	RM-8	A0A
AD8642ARZ	–40°C to +125°C	8-lead SOIC_N	R-8	
AD8642ARZ-REEL7	–40°C to +125°C	8-lead SOIC_N	R-8	
AD8642ARZ-REEL	–40°C to +125°C	8-lead SOIC_N	R-8	
AD8643ARZ	–40°C to +125°C	14-lead SOIC_N	R-14	
AD8643ARZ-REEL7	–40°C to +125°C	14-lead SOIC_N	R-14	
AD8643ARZ-REEL	–40°C to +125°C	14-lead SOIC_N	R-14	
AD8643ACPZ-R2	–40°C to +125°C	16-Lead LFCSP_VQ	CP-16-3	AUA
AD8643ACPZ-REEL7	–40°C to +125°C	16-Lead LFCSP_VQ	CP-16-3	AUA
AD8643ACPZ-REEL	–40°C to +125°C	16-Lead LFCSP_VQ	CP-16-3	AUA

<sup>1</sup> Z = RoHS Compliant Part.

**NOTES**